# **THOMSON-EFCIS**

**Integrated Circuits** 

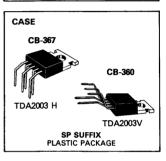
**TDA2003** 

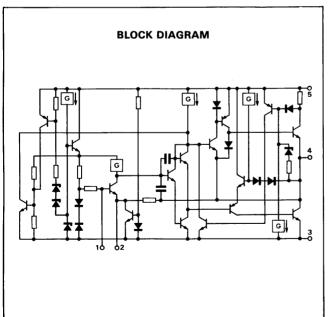
## 10 W CAR RADIO AUDIO AMPLIFIER

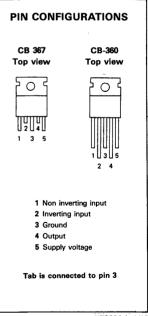
The TDA 2003 has improved performance with the same pin configuration as the TDA 2002. The additional features of TDA 2002; very low number of external components, ease of assembly, space and cost saving, are maintained. The device provides a high output current capability (up to 3.5 A) very low harmonic and cross-over distortion.

Completely safe operation is guaranteed due to protection against DC and AC short circuit between all pins and ground, thermal over-range, load dump voltage surge up to 40 V, polarity inversion and fortuitous open ground.

## 10 W CAR RADIO AUDIO AMPLIFIER







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#### THOMSON-EFCIS

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#### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Peak supply voltage (50 ms)	Vcc	40	v
DC supply voltage	Vcc	28	V
Operating supply voltage	Vcc	18	V
Output peak current (repetitive)	Io	3.5	Α
Output peak current (no repetitive)	l <sub>0</sub>	4.5	A
Power dissipation (T <sub>case</sub> = 90 °C)	P <sub>tot</sub>	20	w
Storage and junction temperature	Tj-T <sub>sta</sub>	- 40 to + 150	°C

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Junction-case thermal resistance	R <sub>th(j-c)</sub>	3 max.	°C/W

#### STATIC CHARACTERISTICS

 $T_{amb}$  = 25 °C;  $V_{CC}$  = 14.4 V; (see figure 1)

(Unless otherwise stated)

Characteristic		Symbol	Min.	Тур.	Max.	Unit
Supply voltage		Vcc	8	_	18	V
Quiescent output voltage	Pin 4	٧o	6.1	6.9	7.7	V
Quiescent drain current	Pin 5	lcc		44	50	mA

#### **DYNAMIC CHARACTERISTICS**

 $T_{amb} = 25 \,^{\circ}\text{C}$ ;  $V_{CC} = 14.4 \,\text{V}$ ;  $A_{V} = 40 \,\text{dB}$ ; (see figure 2)

(Unless otherwise stated)

FIG. 2 - AC TEST CIRCUIT

Characteristic	Symbol	Min.	Тур.	Max.	Unit
Output power (d = 10 %; f = 1kHz)	PO				V
$R_L = 4 \Omega$		5.5	6	_	
$R_L = 2 \Omega$		9	10	_	ŀ
$R_L = 3.2 \Omega$		_	7.5	_	İ
$R_L = 1.6 \Omega$		_	12	-	
Input saturation voltage	VI	300	_	_	mV

FIG. 1 - DC TEST CIRCUIT

• + Vcc C3 100 nF 100 nF C1 C4 1000 μF 1000 μF TDA TDA 2003 10 μF/3 V 2003 =39 nF C5 R1 220 Ω 100 nF R<sub>χ</sub> 39 Ω R1 220 Ω 470 µF C2 470 μF R2 R2 2.2 Ω 2.2 Ω C<sub>X</sub> = 2πBR1  $R_X = 20.R2$ 

## ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	Min.	Тур.	Max.	Unit
Input sensitivity	S				mV
$f = 1 \text{ kHz; } P_{O} = 0.5 \text{ W; } R_{L} = 4 \Omega$		_	14	_	
$P_O = 6 \text{ W}$ ; $R_L = 4 \Omega$		_	55	-	
$P_O = 0.5 \text{ W}; R_L = 2 \Omega$		-	10	-	
$P_O = 10$ W; $R_L = 2 \Omega$			50		
Bandwidth ( - 3 dB)	В				Hz
$P_O = 1 W; R_L = 4 \Omega$			40 to 15.000		
Harmonic distortion	d				%
$0.05 \text{ W} \leq P_{\Omega} \leq 4.5 \text{ W}; R_{1} = 4 \Omega; f = 1 \text{ kHz}$		_	0.15	_	
$0.05 \text{ W} \leqslant P_{\text{O}} \leqslant 7.5 \text{ W}; \text{ R}_{\text{L}} = 2 \Omega; \text{ f} = 1 \text{ kHz}$		_	0.15	_	
Input resistance (f = 1 kHz) Pin 1	Rį	70	150	_	kΩ
Voltage gain ( $R_L = 4 \Omega$ ; f = 1 kHz)	A <sub>V</sub>				dB
Open loop		_	80	_	
Closed loop		39.5	40	40.5	
Input noise voltage	Vn				μ∨
B (-3 dB) = 10 to 25.000 Hz; B (-20 dB) = 4 to 27.000 Hz		_	1	5	
Input noise current	in				pA
B (- 3 dB) = 10 to 25.000 Hz; B (- 20 dB) = 4 to 27.000 Hz		_	60	200	
Efficiency	η				%
$f = 1 \text{ kHz; } P_{\Omega} = 6 \text{ W; } R_{L} = 4 \Omega$		_	69	_	
$P_0 = 10 \text{ W; } R_L = 2 \Omega$		_	, 65		
Supply voltage rejection	SVR				dB
$f = 100 \text{ Hz}$ ; $V_{ripple} = 0.5 \text{ V}$ ; $R_G = 10 \text{ k}\Omega$ ; $R_L = 4 \Omega$		30	36	i –	

## TYPICAL CHARACTERISTICS

FIG. 3 — QUIESCENT OUTPUT VOLTAGE VERSUS SUPPLY VOLTAGE

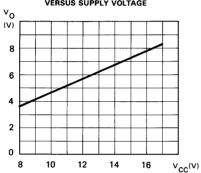


FIG. 4 — QUIESCENT DRAIN CURRENT VERSUS SUPPLY VOLTAGE

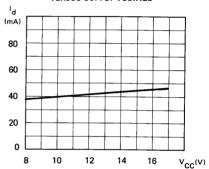


FIG. 5 — OUTPUT POWER VERSUS SUPPLY VOLTAGE

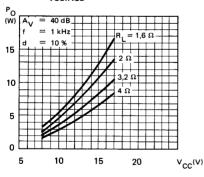
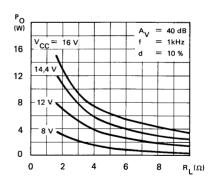


FIG. 6 - OUTPUT POWER VERSUS RL



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#### TYPICAL CHARACTERISTICS (continued)

FIG. 7 — GAIN VERSUS INPUT SENSITIVITY

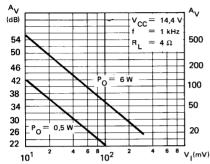


FIG. 8 - GAIN VERSUS INPUT SENSITIVITY

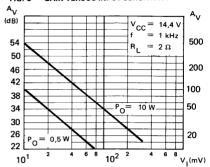


FIG. 9 — DISTORTION VERSUS OUTPUT POWER

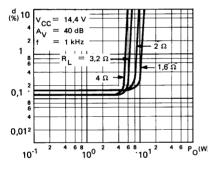


FIG. 10 — DISTORTION VERSUS FRE-QUENCY

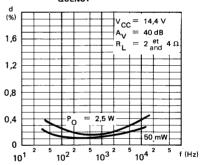


FIG. 11 – SUPPLY VOLTAGE REJECTION
VERSUS VOLTAGE GAIN

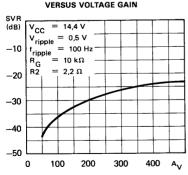
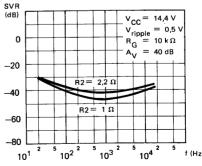


FIG. 12 — SUPPLY VOLTAGE REJECTION VERSUS FREQUENCY



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## TYPICAL CHARACTERISTICS (continued)

FIG. 13 — POWER DISSIPATION AND EFFI-CIENCY VERSUS OUTPUT POWER

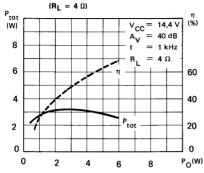


FIG. 14 — POWER DISSIPATION AND EFFI-CIENCY VERSUS OUTPUT POWER

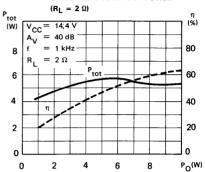


FIG. 15 — MAXIMUM POWER DISSIPATION
VERSUS SUPPLY VOLTAGE (SINE

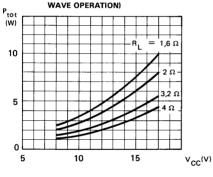


FIG. 16 — MAXIMUM ALLOWABLE POWER
DISSIPATION VERSUS AMBIENT

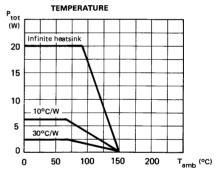


FIG. 17 — TYPICAL VALUES OF CAPACITOR
(C<sub>X</sub>) FOR DIFFERENT VALUES OF
FREQUENCY RESPONSE (B)

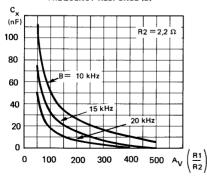
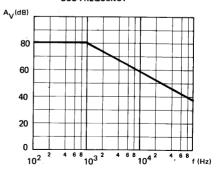


FIG. 18 — OPEN LOOP VOLTAGE GAIN VER-SUS FREQUENCY



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## PRATICAL CONSIDERATIONS

Component	Recommended value	Purpose	Larger than recommended value	Smaller than recommended value
C1	10 μF	Input DC decoupling		Noise at switch-on, switch-off
C2	470 μF	Ripple rejection		Degradation of SVR
C3	0,1 μF	Supply bypassing		Danger of oscillation
C4	1000 μF	Output coupling to load		Higher low frequency cutoff
C5	0,1 μF	Frequency stability		Danger of oscillation at high frequencies with inductive loads
c <sub>x</sub>	$ \cong \frac{1}{2\pi \text{ BR1}} $	Upper frequency cutoff	Lower bandwidth	Larger bandwidth
R1	(A <sub>V</sub> – 1) • R2	Setting of gain		Increase of drain current
R2	2,2 Ω	Setting of gain and SVR	Degradation of SVR	
R3	1 Ω	Frequency stability	Danger of oscillation at high frequencies with inductive loads	
R <sub>X</sub>	≅ 20 R2	Upper frequency cutoff	Poor high frequency attenuation	Danger of oscillation

## PRINTED CIRCUIT BOARD

The layout shown in figure 20 is recommended. If different layours are used, the ground points of input 1 and input 2 must be well decoupled from the ground of the output through which a rather high current flows.

#### **ASSEMBLY SUGGESTION**

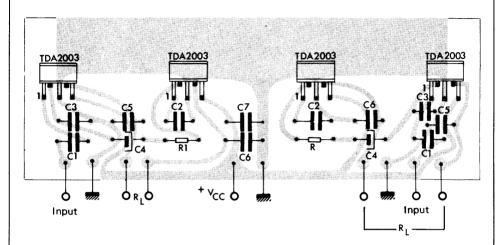
The device does not require insulation between the package and the heatsink. Pin lenght should be as short as possible. The soldering temperature must not exceed 260 °C for .12 seconds.

#### **APPLICATION SUGGESTION**

The recommended component values are those shown in the application circuits of fig. 19. Different values can be used. The following table is intended to aid the car-radio designer.

#### APPLICATION INFORMATION (continued)

FIG. 25 — P.C. BOARD AND COMPONENT LAYOUT FOR
THE LOW-COST BRIDGE AMPLIFIER OF FIG. 23
STEREO VERSION (1/1 SCALE)



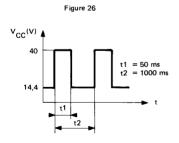
#### **BUILT-IN PROTECTION SYSTEMS**

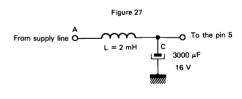
#### LOAD DUMP VOLTAGE SURGE

The TDA2003 has a circuit which enables is to withstand a voltage pulse train, on pin 5, of the type shown in fig. 26. If the supply voltage peaks to more than 40 V, then an LC filter must be inserted between the supply and pin 5, in order

to assure that the pulses at pin 5 will be held within the limits shown in fig. 26.

A suggested LC network is shown in fig. 27. With this network, a train of pulses with amplitude up to 120 V and width 2 ms can be applied at point A.





## SHORT-CIRCUIT (AC AND DC CONDITIONS)

The TDA2003 can withstand a permanent short-circuit on the output for a supply voltage up to 16  $\rm V.$ 

#### BUILT-IN PROTECTION SYSTEMS (continued)

#### POLARITY INVERSION

High current (up to 5 A) can be handled by the device with no damage for a longer period than the blow-out time of a quick 1 A fuse (normally connected in series with the supply). This feature is added to avoid destruction if, during fitting to the car, a mistake on the connection of the supply is made.

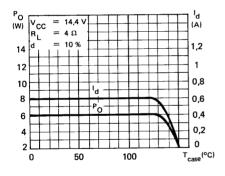
## **OPEN GROUND**

When the radio is in the ON condition and the ground is accidentally opened, a standard audio amplifier will be damaged. On the TDA2003 protection diodes are included to avoid any damage.

#### INDUCTIVE LOAD

A protection diode is provided between pin 4 and 5 (see the internal schematic diagram) to allow use of the TDA2003 with inductive loads. In particular, the TDA2003 can drive a coupling transformer for audio modulation.

#### FIG. 28 — OUTPUT POWER AND DRAIN CURRENT VERSUS CASE TEMPE-BATURE



#### DC VOLTAGE

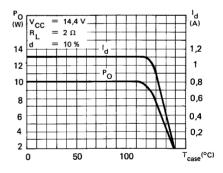
The maximum operating DC voltage on the TDA2003 is 18 V. However the device can withstand a DC voltage up to 28 V with to damage. This could occur during winter if two batteries are series connected to crank the engine.

## THERMAL SHUT-DOWN

The presence of a thermal limiting circuit offers the following advantages:

- 1 An overload on the output (even if it is permanent), or an excessive ambient temperature can be easily withstood.
- 2 The heatsink can have a smaller factor of safety compared with that of a conventional circuit. There is no device damage in the case of excessive junction temperature: all that happens is that PO (and therefore Ptot) and I<sub>H</sub> are reduced (figs. 28 and 29).

FIG. 29 — OUTPUT POWER AND DRAIN CURRENT VERSUS CASE TEMPE-RATURE



## PRATICAL CONSIDERATIONS

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